

Vishay Siliconix

# N-Channel 25 V (D-S) MOSFET

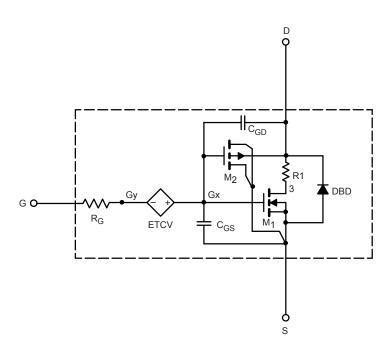
#### **DESCRIPTION**

The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage. A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

#### SUBCIRCUIT MODEL SCHEMATIC

#### **CHARACTERISTICS**

- N-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- Model the Gate Charge



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



# **SPICE Device Model SiR408DP**

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SPECIFICATIONS (TJ = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	1.2	-	٧
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	0.0051	0.0052	Ω
		$V_{GS} = 4.5 \text{ V}, I_D = 15 \text{ A}$	0.0064	0.0064	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_D = 20 \text{ A}$	74	85	S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>S</sub> = 4 A	0.74	0.75	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 15 V, V <sub>GS</sub> = 0 V, f = 1 MHz	1230	1230	pF
Output Capacitance	C <sub>oss</sub>		358	315	
Reverse Transfer Capacitance	C <sub>rss</sub>		102	115	
Total Gate Charge	Qg	$V_{DS} = 12.5 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$	21	21.5	nC
		$V_{DS} = 12.5 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$	10	9.3	
Gate-Source Charge	Q <sub>gs</sub>		3.2	3.2	
Gate-Drain Charge	$Q_{gd}$		2.6	2.6	

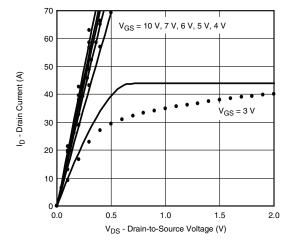
#### **Notes**

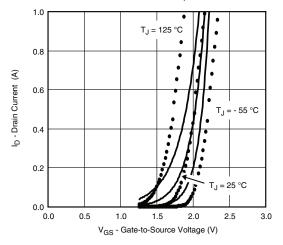
- a. Pulse test; pulse width  $\leq 300~\mu s,~duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

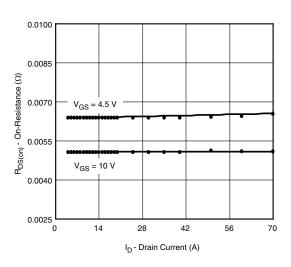
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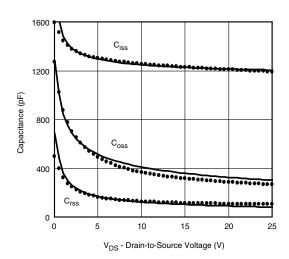
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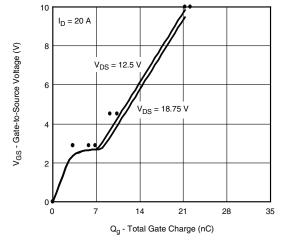
### **COMPARISON OF MODEL WITH MEASURED DATA** (TJ = 25 °C, unless otherwise noted)

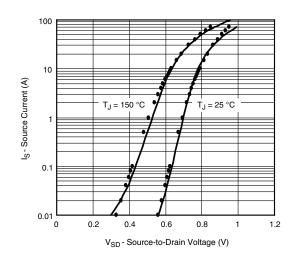












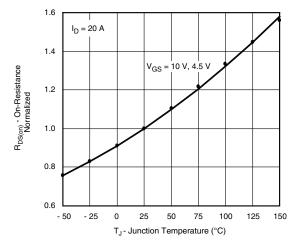
#### Note

· Dots and squares represent measured data.

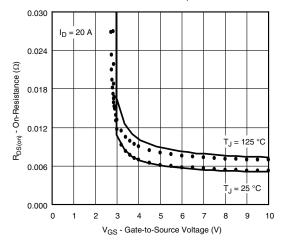
# **SPICE Device Model SiR408DP**

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### **COMPARISON OF MODEL WITH MEASURED DATA** (TJ = 25 °C, unless otherwise noted)



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#### Note

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